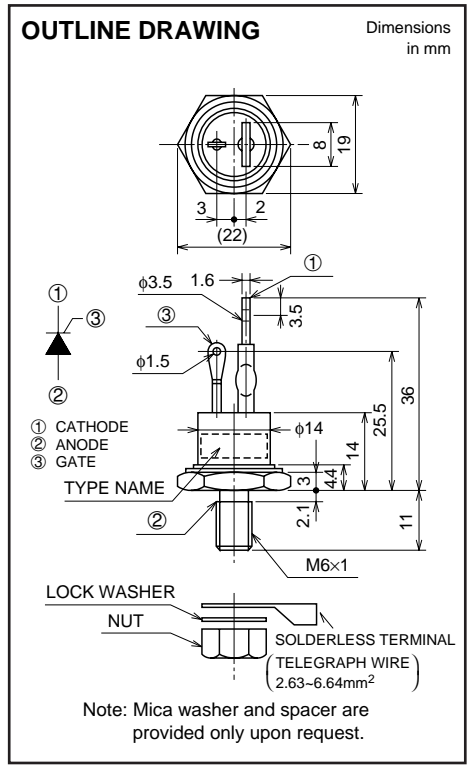


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MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE



APPLICATION

DC motor control, electric furnace control, static switches, DC supply

MAXIMUM RATINGS

Symbol	Parameter	Voltage class					Unit
		8	12	16	20	24	
VRRM	Repetitive peak reverse voltage	400	600	800	1000	1200	V
VRSM	Non-repetitive peak reverse voltage	480	720	960	1200	1350	V
VR (DC)	DC reverse voltage	320	480	640	800	960	V
VDRM	Repetitive peak off-state voltage	400	600	800	1000	1200	V
VDSM	Non-repetitive peak off-state voltage	480	720	980	1000	1200	V
VD (DC)	DC off-state voltage	320	480	640	800	960	V

Symbol	Parameter	Conditions	Ratings	Unit
I_T (RMS)	RMS on-state current		31.5	A
I_T (AV)	Average on-state current	Commercial frequency, sine half wave, 180° conduction, $T_c=86^\circ\text{C}$	20	A
I_{TSM}	Surge on-state current	60Hz sine half wave 1 full cycle, peak value, non-repetitive	300	A
i^2t	i^2t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	380	A ² s
di/dt	Critical rate of rise of on-state current	$V_D=1/2V_{DRM}$, $I_{TM}=60\text{A}$, $I_G=0.1\text{A}$, $T_j=25^\circ\text{C}$, $f=60\text{Hz}$	100	A/ μs
PGM	Peak gate power dissipation		5.0	W
PG (AV)	Average gate power dissipation		0.5	W
VFGM	Peak gate forward voltage		10	V
VRGM	Peak gate reverse voltage		5	V
IFGM	Peak gate forward current		2	A
T_j	Junction temperature		-30 ~ +125	°C
T_{stg}	Storage temperature		-30 ~ +125	°C
—	Mounting torque		30	kg-cm
			2.94	N-m
—	Weight	Typical value	20	g

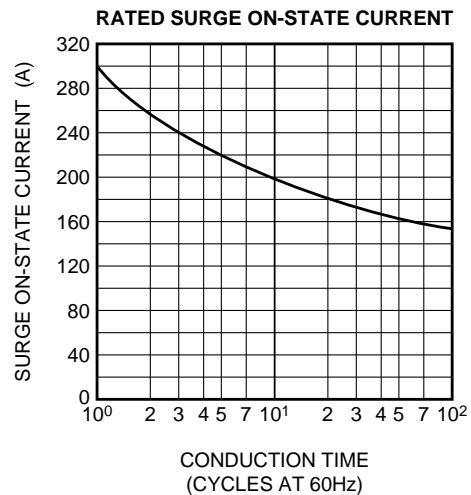
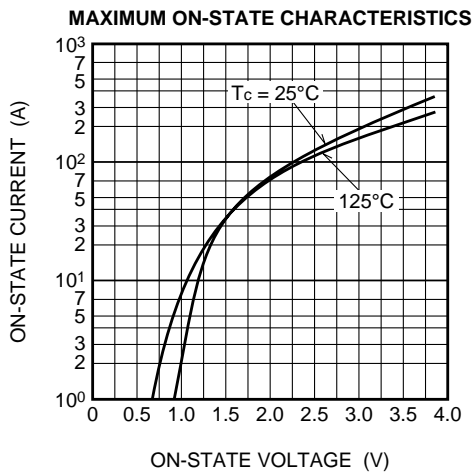
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**MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE**

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	$T_j=125^\circ\text{C}$, V_{RRM} applied	—	—	4.0	mA
IDRM	Repetitive peak off-state current	$T_j=125^\circ\text{C}$, V_{DRM} applied	—	—	4.0	mA
V_{TM}	On-state voltage	$T_c=25^\circ\text{C}$, $I_{TM}=60\text{A}$, Instantaneous value	—	—	1.8	V
dv/dt	Critical-rate of rise of off-state voltage	$T_j=125^\circ\text{C}$, $V_D=2/3V_{DRM}$	50	—	—	V
VGT	Gate trigger voltage	$T_j=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=0.5\text{A}$	—	—	3.0	V
VGD	Gate non-trigger voltage	$T_j=125^\circ\text{C}$, $V_D=1/2V_{DRM}$	0.25	—	—	V
IGT	Gate trigger current	$T_j=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=0.5\text{A}$	—	—	50	mA
tgt	Turn-on time	$T_c=25^\circ\text{C}$, $V_D=100\text{V}$, $I_T=15\text{A}$, $I_G=0.1\text{A}$	—	—	10	μs
$R_{th(j-c)}$	Thermal resistance	Junction to case	—	—	1.0	$^\circ\text{C/W}$
$R_{th(c-f)}$	Contact thermal resistance	Case to fin	—	—	0.4	$^\circ\text{C/W}$

PERFORMANCE CURVES

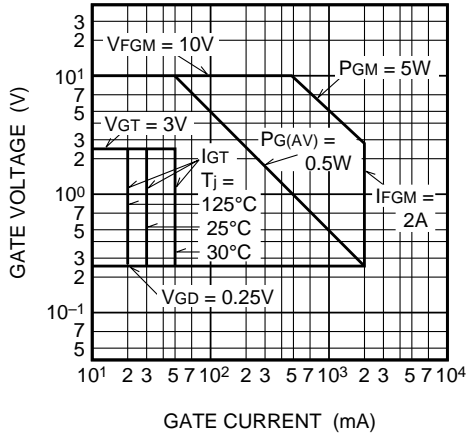


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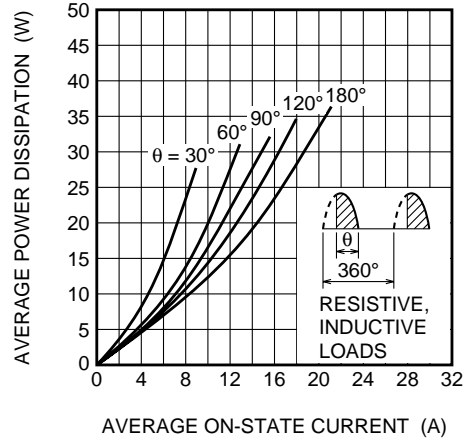
MEDIUM POWER USE

NON-INSULATED ALUMINUM TYPE, GLASS PASSIVATION TYPE

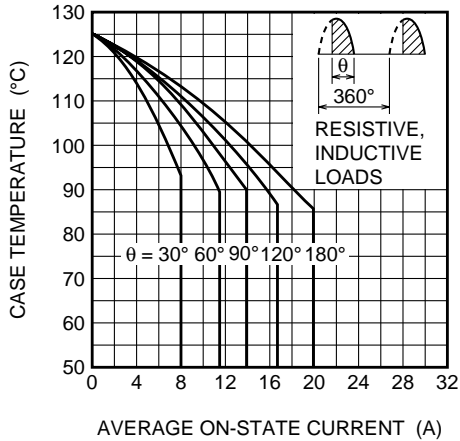
GATE CHARACTERISTICS



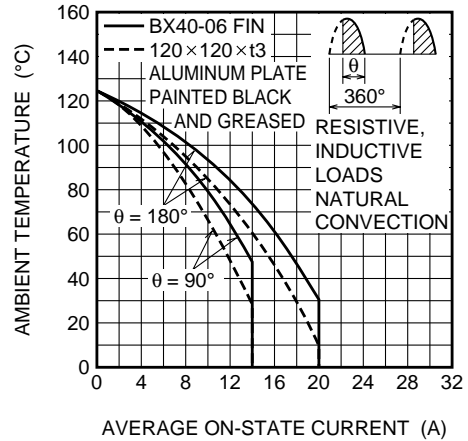
MAXIMUM AVERAGE POWER DISSIPATION (SINGLE-PHASE HALF WAVE)



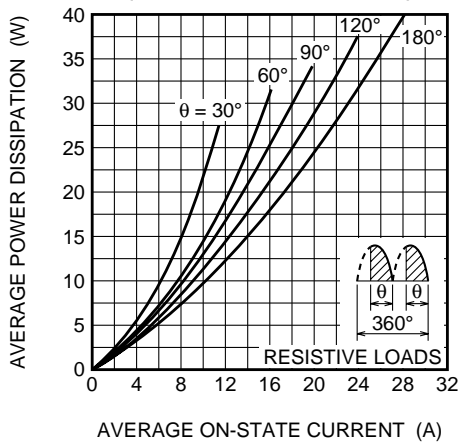
ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE HALF WAVE)



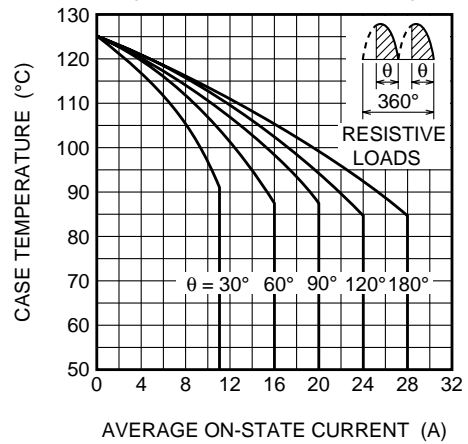
ALLOWABLE AMBIENT TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE HALF WAVE)



MAXIMUM AVERAGE POWER DISSIPATION (SINGLE-PHASE FULL WAVE)



ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE FULL WAVE)

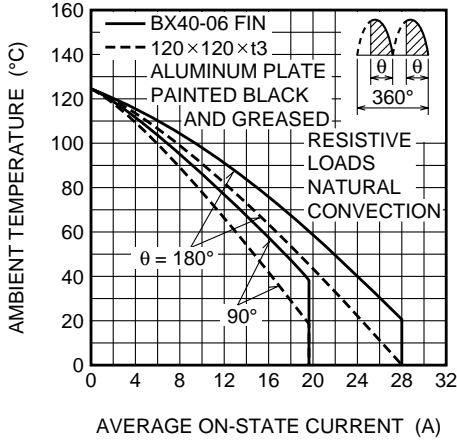


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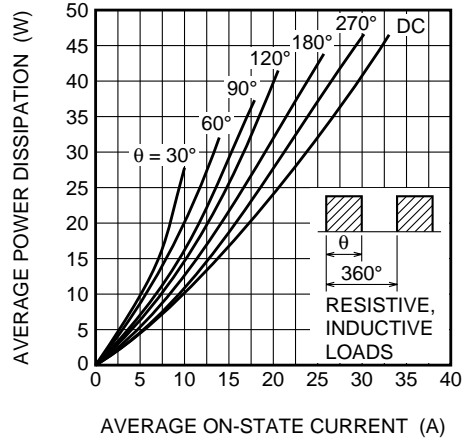
MEDIUM POWER USE

NON-INSULATED TYPE, GLASS PASSIVATION TYPE

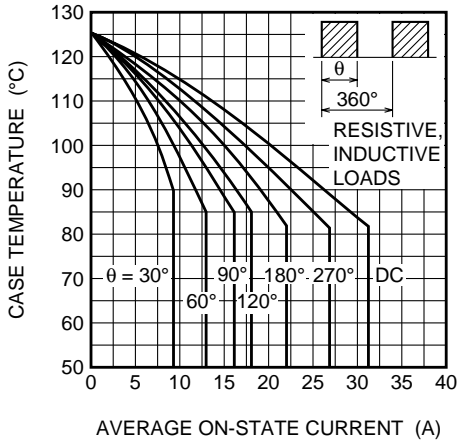
ALLOWABLE AMBIENT TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE FULL WAVE)



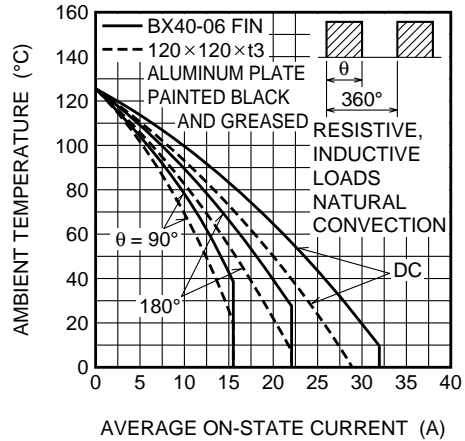
MAXIMUM AVERAGE POWER DISSIPATION (RECTANGULAR WAVE)



ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (RECTANGULAR WAVE)



ALLOWABLE AMBIENT TEMPERATURE VS. AVERAGE ON-STATE CURRENT (RECTANGULAR WAVE)



CR20F BLOCK FIN BX40-06 OUTLINE DRAWING (Unit: mm)

